

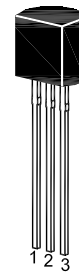
9014-HAF

NPN Silicon Epitaxial Planar Transistor

The transistor is subdivided into four groups, A, B, C and D, according to its DC current gain. As complementary type the PNP transistor 9015 is recommended.

Features

- On special request, these transistors can be
- manufactured in different pin configurations
- Halogen and Antimony Free(HAF), RoHS compliant



1. Emitter 2. Base 3. Collector
TO-92 Plastic Package

Applications

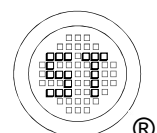
- For switching and AF amplifier

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	50	V
Collector Emitter Voltage	V_{CEO}	45	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current	I_C	100	mA
Power Dissipation	P_{tot}	450	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Thermal Resistance Ratings

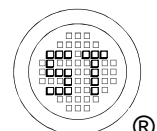
Parameter	Symbol	Max.	Unit
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	278	$^\circ\text{C/W}$



9014-HAF

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $V_{CE} = 5\text{ V}$, $I_C = 1\text{ mA}$ Current Gain Group	A	h_{FE}	60	-	150	-
	B	h_{FE}	100	-	300	-
	C	h_{FE}	200	-	600	-
	D	h_{FE}	400	-	1000	-
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$	I_{CBO}	-	-	50	nA	
Emitter Base Cutoff Current at $V_{EB} = 5\text{ V}$	I_{EBO}	-	-	50	nA	
Collector Base Breakdown Voltage at $I_C = 100\text{ }\mu\text{A}$	$V_{(BR)CBO}$	50	-	-	V	
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	45	-	-	V	
Emitter Base Breakdown Voltage at $I_E = 100\text{ }\mu\text{A}$	$V_{(BR)EBO}$	5	-	-	V	
Collector Emitter Saturation Voltage at $I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$	$V_{CE(sat)}$	-	-	0.25	V	
Gain Bandwidth Product at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$	f_T	-	300	-	MHz	
Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	-	6	pF	



Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

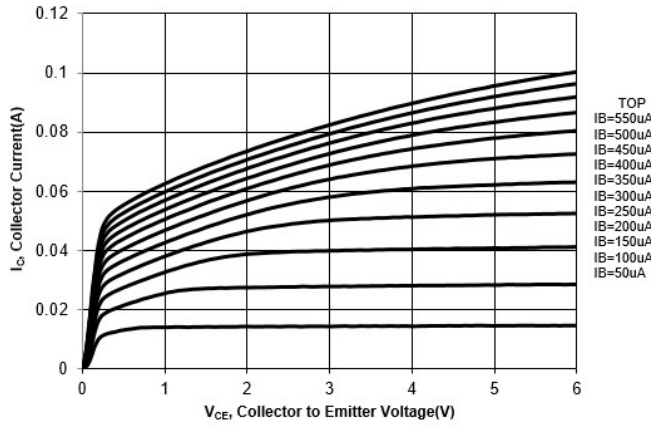


Fig. 2 Collector Current vs. Base to Emitter Voltage

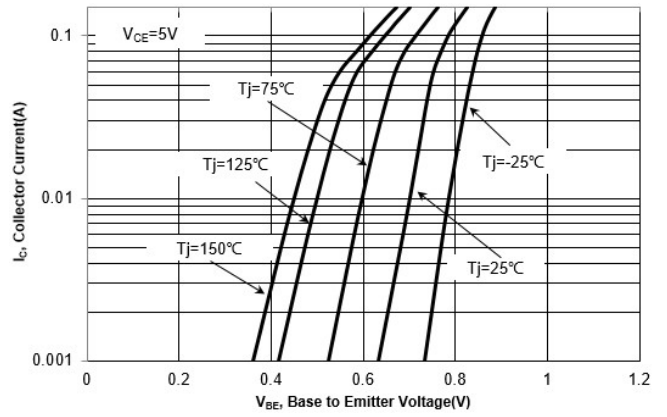


Fig. 3 DC Current Gain vs. Collector Current

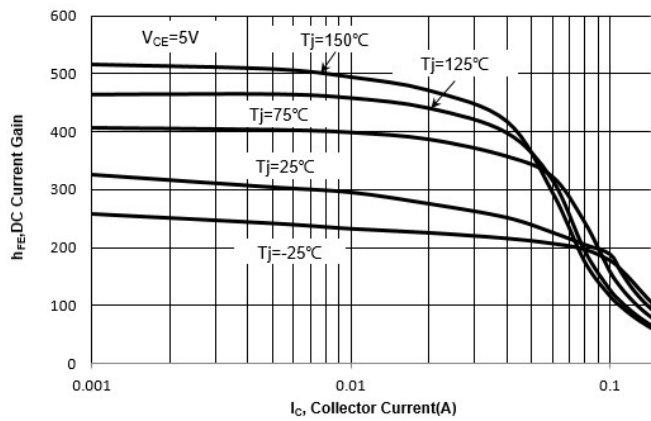
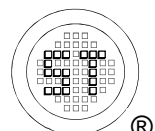
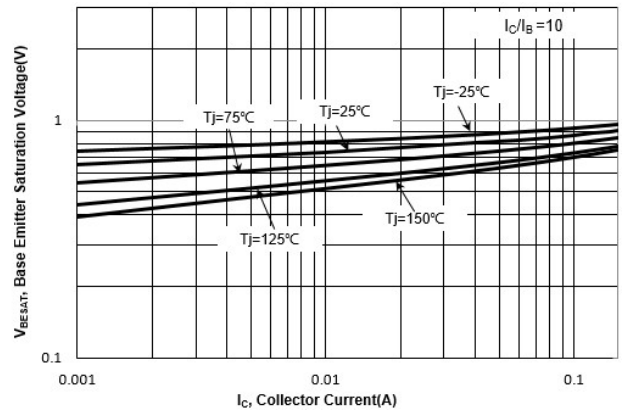


Fig. 4 V_{BESAT} vs. Collector Current



Electrical Characteristics Curves

Fig. 5 V_{CESAT} vs. Collector Current

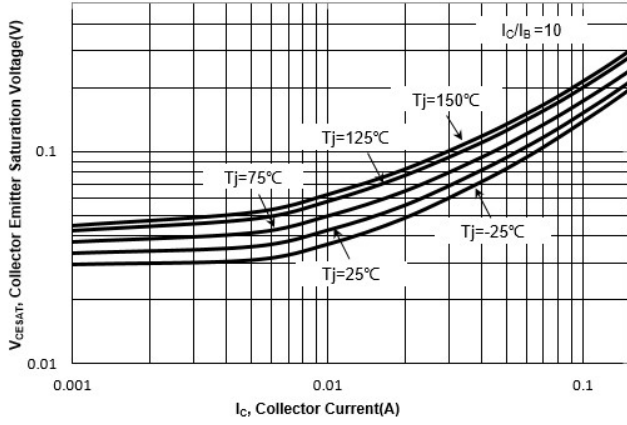


Fig. 6 Output Capacitance

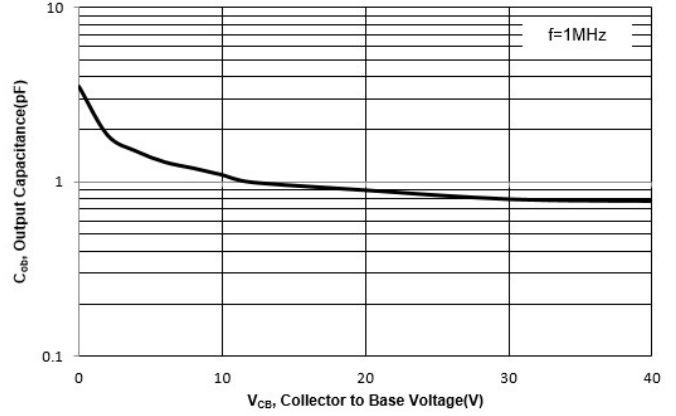
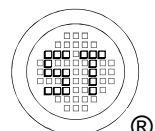
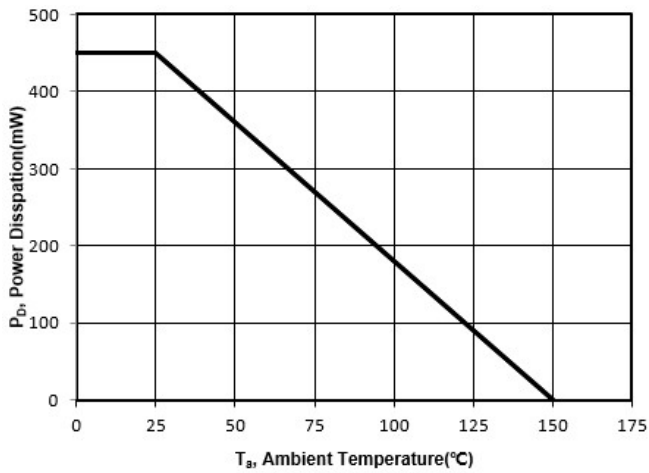
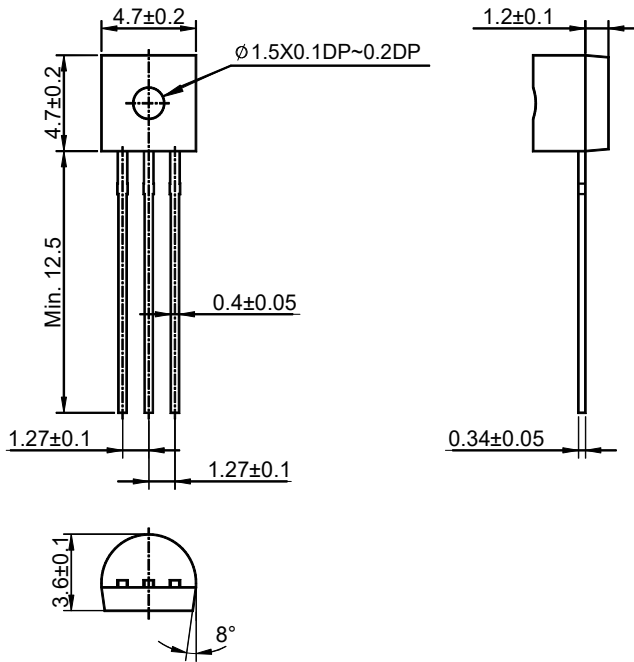


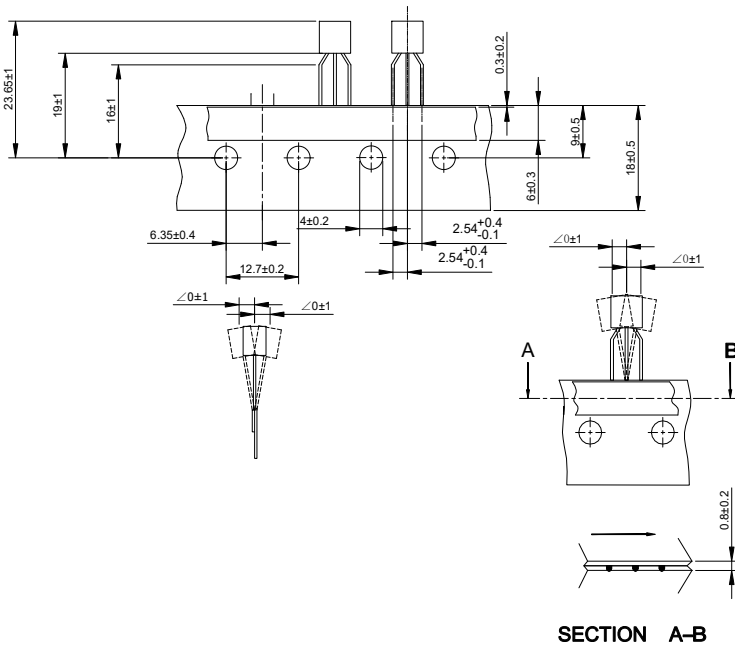
Fig. 7 Power Derating Curve



TO-92 Package Outline (Dimensions in millimeters)



TO-92 Ammo-Pack Outline (Dimensions in millimeters)



SECTION A-B

Packing information

Package	Bulk Packing			Ammo-Packing	
	Per Bag Qty	Per Box Qty	Per Carton Qty	Per Box Qty	Per Carton Qty
TO-92	1,000	5,000	50,000	4,000	20,000

